

■ Features

- Fast response time
- High analytic
- Cut-off visible wavelength $\lambda_p=940\text{nm}$
- High sensitivity
- Pb free
- This product itself will remain within RoHS compliant version.

■ Descriptions

The ITR9909-R(JB) consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing .

The phototransistor does not receive radiation from IR LED in normal situation, but when an object comes closer, the radiation is reflected by the object and phototransistor receives the more radiation as closer the object comes.

For additional component information, please refer to IR and PT.

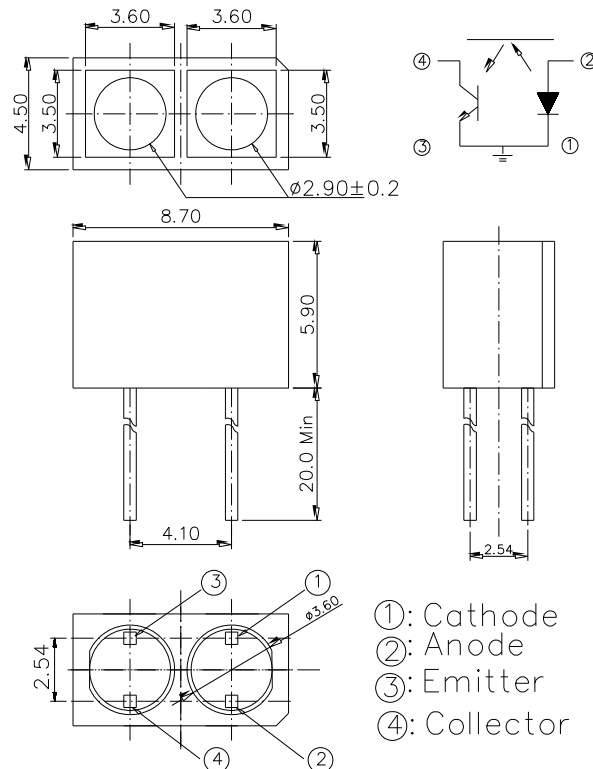
■ Applications

- Mouse Copier
- Switch Scanner
- Floppy disk driver
- Non-contact Switching
- For Direct Board

■ Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAlAs	Blue
PT	Silicon	Black

■ Package Dimensions



Notes:

1. All dimensions are in millimeters.
2. Tolerances unless dimensions ± 0.25 mm.
3. Lead spacing is measured where the lead emerge from the package.
4. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
5. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
6. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	100	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤ 100μs, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	100	mW
	Collector Current	I _C	50	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		Topr	-25~+85	°C
Storage Temperature		Tstg	-40~+100	°C
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	°C

(*1) tw=100 μsec., T=10 msec. (*2) t=5 Sec

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V _{F1}	---	1.2	1.5	V	I _F =20mA
		V _{F2}	---	1.4	1.85		I _F =100mA, tp=100μs, tp/T=0.01
		V _{F3}	---	2.6	4.0		I _F =1A, tp=100μs, tp/T=0.01
	Reverse Current	I _R	---	---	10	μA	V _R =5V
	Peak Wavelength	λ _p	---	940	---	nm	I _F =20mA
	View Angle	2θ1/2	---	60	---	Deg	I _F =20mA
Output	Dark Current	I _{CEO}	---	---	100	nA	V _{CE} =20V, Ee=0mW/cm ²
	C-E Saturation Voltage	V _{CE(sat)}	---	---	0.4	V	I _C =2mA, Ee=1mW/cm ²
Transfer Characteristics	Collect Current	I _{C(ON)A}	0.2	---	1.5	mA	V _{CE} =5V
		I _{C(ON)B}	1.5	---	3.0		I _F =20mA
	Rise time	t _r	---	15	---	μsec	V _{CE} =5V
	Fall time	t _f	---	15	---	μsec	I _C =1mA R _L =1KΩ

Tolerances : ± 10%

■ Typical Electrical/Optical/Characteristics Curves for IR

Fig.1 Forward Current vs.

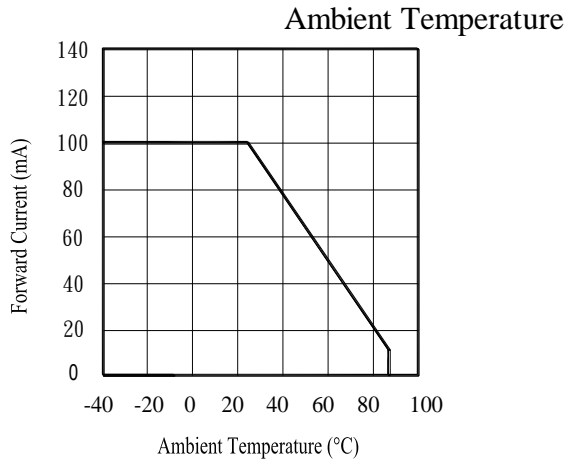


Fig.2 Spectral Distribution

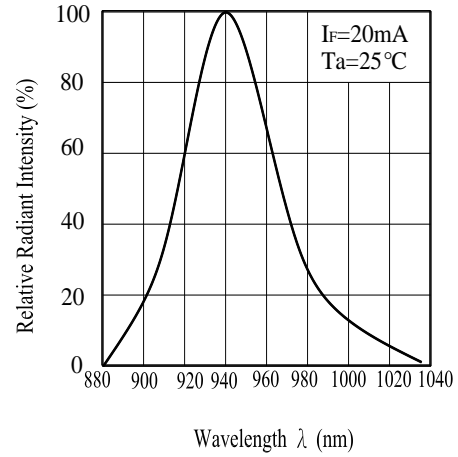


Fig.3 Radiant Intensity vs.

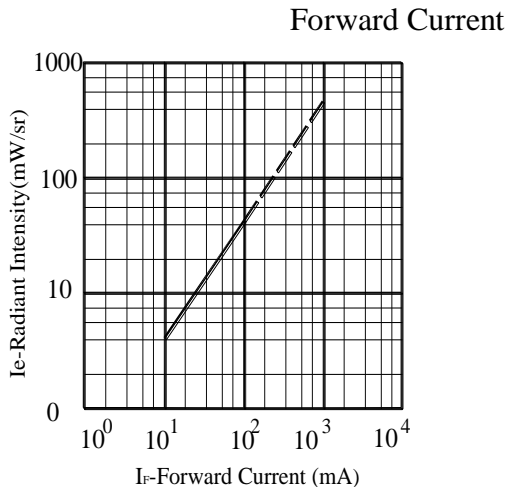
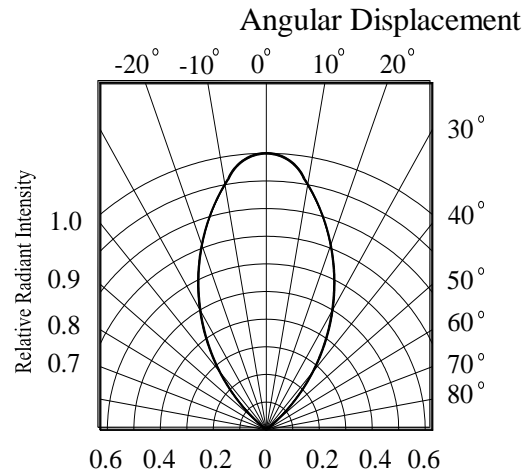


Fig.4 Relative Radiant Intensity vs.



Typical Electrical/Optical/Characteristics Curves for PT

Fig.1 Collector Power Dissipation vs.

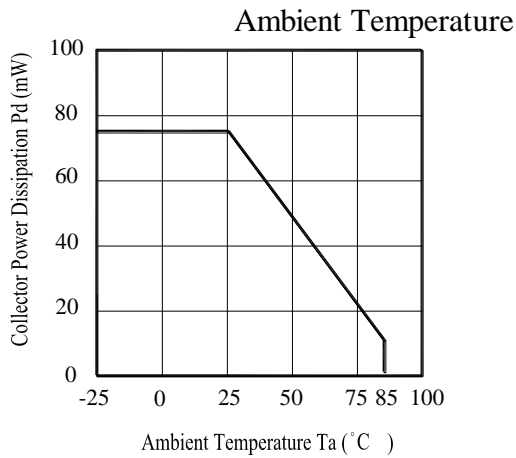


Fig.2 Spectral Sensitivity

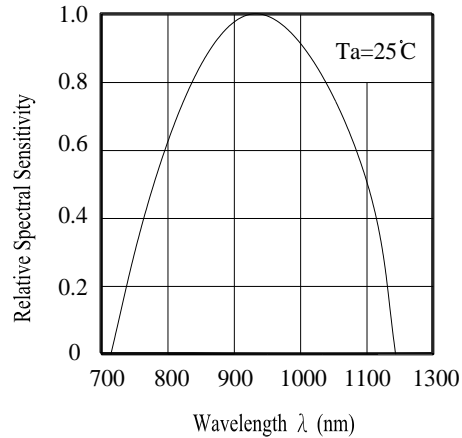


Fig.3 Relative Collector Current vs..

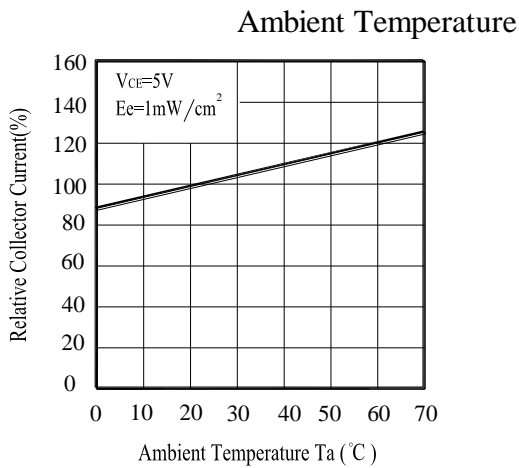


Fig.4 Collector Current vs.

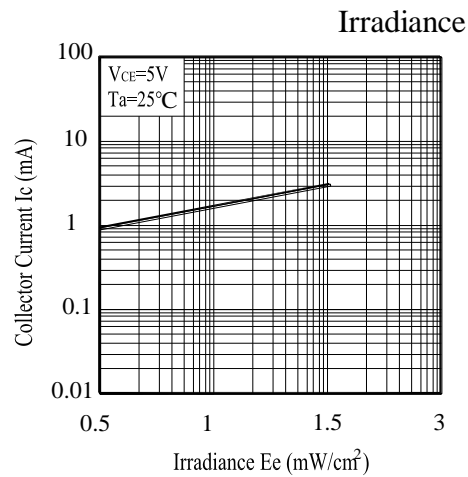


Fig.5 Collector Dark Current vs.

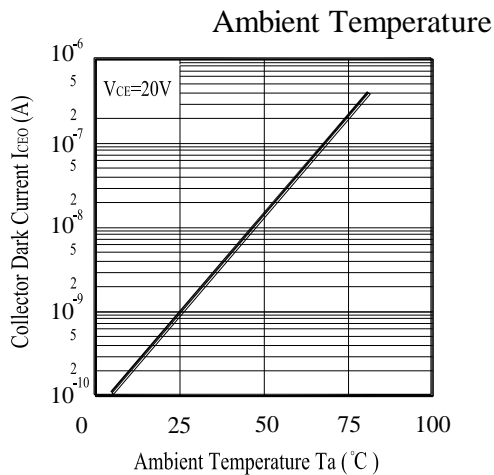
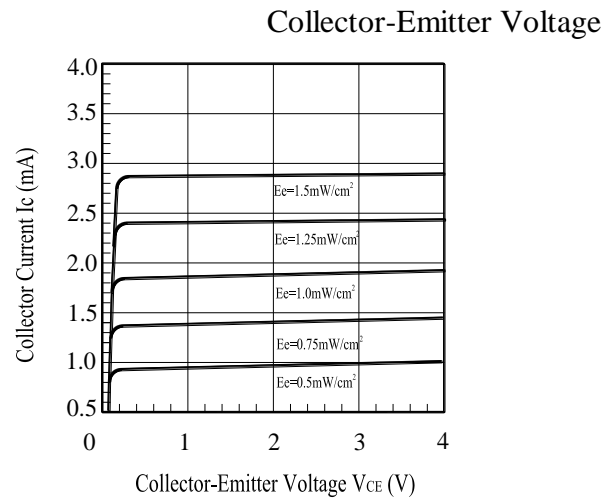


Fig.6 Collector Current vs.



■ Packing Quantity Specification

150 pcs/1bag , 5 bags/1box , 10 boxes/1carton

■ Label Form Specification



CPN: Customer's Production Number

P/N : Production Number

QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

X: Month

Reference: Identify Label Number

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